VEC2315

Power MOSFET –60V, 137mΩ, –2.5A, Dual P-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

Features

- Low On-Resistance
- 4V drive
- Low-Profile Package
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

Typical Applications

• Motor Driver

SPECIFICATIONS ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit		
Drain to Source Voltage	VDSS	-60	V		
Gate to Source Voltage	VGSS	±20	V		
Drain Current (DC)	ID	-2.5	А		
Drain Current (Pulse) PW $\leq 10\mu$ s, duty cycle $\leq 1\%$	IDP	-10	А		
Power Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm) 1unit	PD	0.9	W		
Total Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm)	PŢ	1.0	W		
Junction Temperature	Tj	150	°C		
Storage Temperature	Tstg	–55 to +150	°C		

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² \times 0.8mm) 1unit	$R_{\theta J A}$	138.8	°C/W
(900mm × 0.8mm) Tunit			

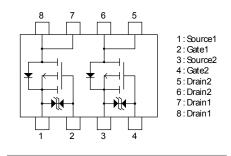


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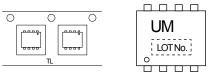
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VDSS	R _{DS} (on) Max	ID Max
	137mΩ@ –10V	
-60V	180mΩ@ –4.5V	-2.5A
	194mΩ@ –4V	

ELECTRICAL CONNECTION P-Channel



PACKING TYPE : TL MARKING



ORDERING INFORMATION

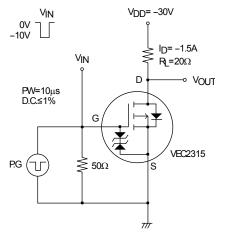
See detailed ordering and shipping information on page 5 of this data sheet.

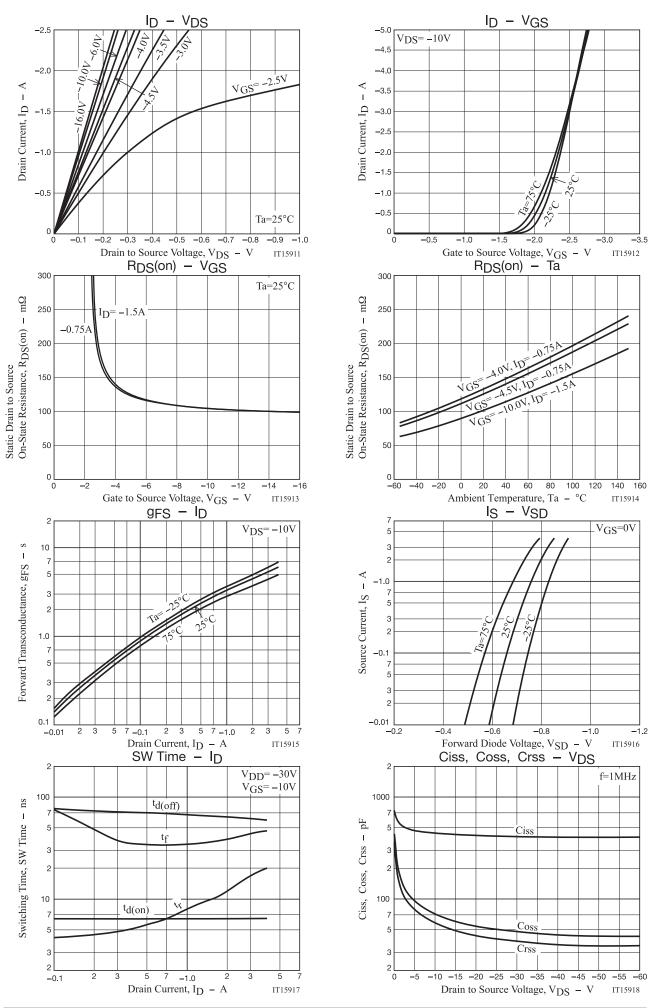
Parameter	Symbol	Conditions	Value			Unit
Farameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V			-1	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μA
Gate Threshold Voltage	VGS(th)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transconductance	9FS	V _{DS} =-10V, I _D =-1.5A		3.9		S
	R _{DS} (on)1	ID=-1.5A, VGS=-10V		105	137	mΩ
Static Drain to Source On-State Resistance	R _{DS} (on)2	ID=-0.75A, VGS=-4.5V		128	180	mΩ
Resistance	R _{DS} (on)3	ID=-0.75A, VGS=-4V		138	194	mΩ
Input Capacitance	Ciss			420		pF
Output Capacitance	Coss	V _{DS} =–20V, f=1MHz		54		pF
Reverse Transfer Capacitance	Crss			44		pF
Turn-ON Delay Time	t _d (on)			6.4		ns
Rise Time	tr			9.8		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		65		ns
Fall Time	tf			36		ns
Total Gate Charge	Qg			11		nC
Gate to Source Charge G	Qgs	V _{DS} =-30V, V _{GS} =-10V, I _D =-2.5A		1.4		nC
Gate to Drain "Miller" Charge	Qgd	1		2		nC
Forward Diode Voltage	V _{SD}	IS=-2.5A, VGS=0V		-0.83	-1.2	V

ELECTRICAL CHARACTERISTICS at $Ta = 25^{\circ}C$ (Note 2)

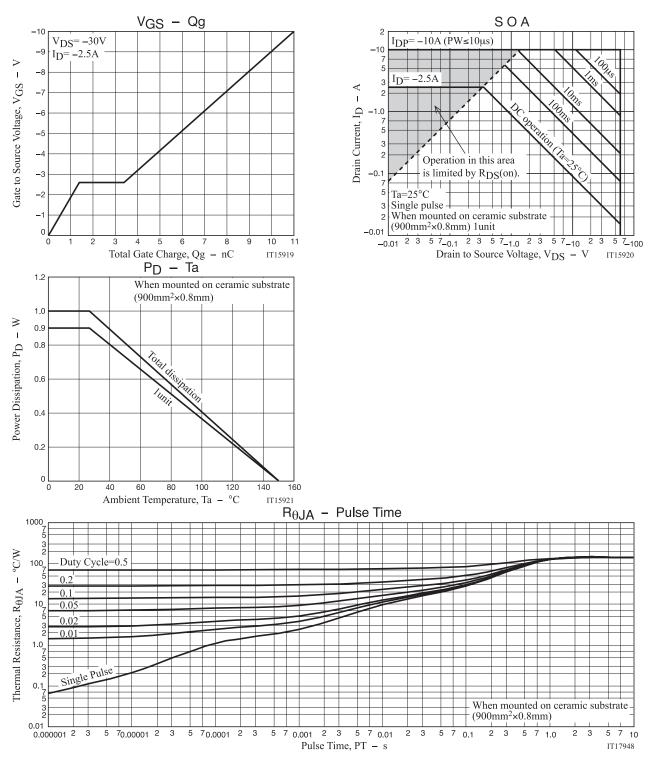
Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit





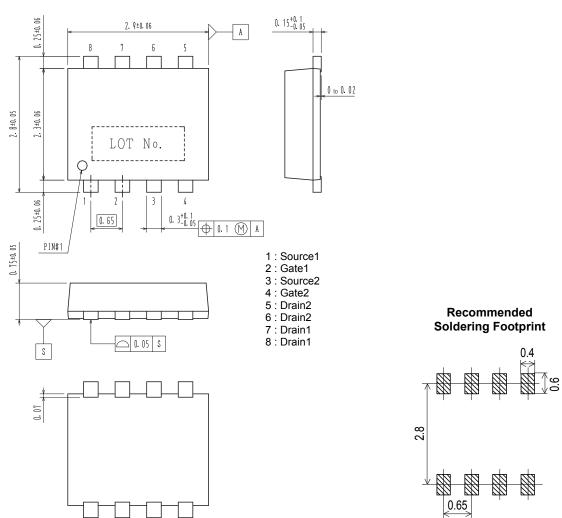
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PACKAGE DIMENSIONS

unit : mm





ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)			
VEC2315-TL-H	1154	SOT-28FL / VEC8	3,000 / Tape & Reel			
VEC2315-TL-W	UM	(Pb-Free / Halogen Free)				

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the VEC2315 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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